

TECHNICAL DATA
DATA SHEET 547, REV. Formerly Part Number SHD2182/A/B

HERMETIC POWER MOSFET N-CHANNEL

FEATURES:

- · 100 Volt, .055 Ohm, 38A MOSFET
- Isolated Hermetic Metal Package
- Fast Switching
- Low R_{DS (on)}
- Equivalent to IRFM150

MAXIMUM RATINGS

ALL RATINGS ARE AT $T_{\rm C}$ = 25°C UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MIN.	TYP.	MAX.	UNITS
GATE TO SOURCE VOLTAGE	V_{GS}	-	-	±20	Volts
ON-STATE DRAIN CURRENT	I _D	-	-	38	Amps
PULSED DRAIN CURRENT @ $T_C = 25^{\circ}C$	I _{DM}	ı	ı	152	Amps
OPERATING AND STORAGE TEMPERATURE	T_J/T_{STG}	-55	-	+150	°C
TOTAL DEVICE DISSIPATION @ $T_C = 25^{\circ}C$	P_{D}	-	-	200	Watts
THERMAL RESISTANCE, JUNCTION TO CASE	R_{thJC}	-	-	0.6	°C/W

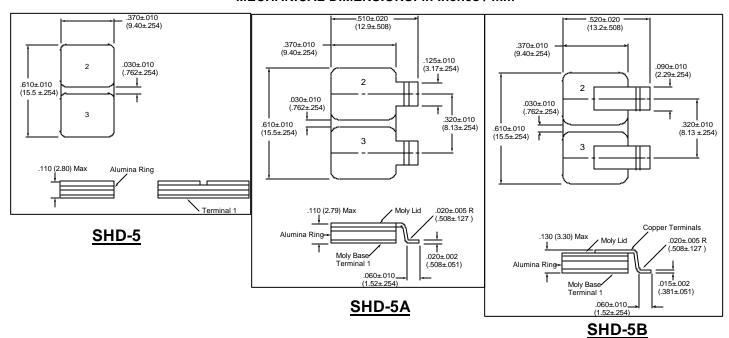
ELECTRICAL CHARACTERISTICS

DRAIN TO SOURCE BREAKDOWN VOLTA	GE	BV _{DSS}	100	-	-	Volts
$V_{GS} = 0$	$V, I_D = 1.0 \text{ mA}$					
STATIC DRAIN TO SOURCE ON STATE RE	ESISTANCE					
$V_{GS} = 0$	10V, $I_D = 24A$	R _{DS(ON)}	-	-	0.055	Ω
GATE THRESHOLD VOLTAGE V _{DS} = V _G	$_{SS}$, $I_{D} = 250 \mu A$	$V_{GS(th)}$	2.0	-	4.0	Volts
FORWARD TRANSCONDUCTANCE						S(1/Ω)
	$V_{DS} \ge 15V$,	9 _{fs}	9.0	-	-	
	$I_{DS} = 24A$					
ZERO GATE VOLTAGE DRAIN CURRENT						
$V_{DS} = 0.8 \text{ x Max. rate}$	•	I_{DSS}	-	-	25	μΑ
	$T_J = 25^{\circ}C$					
ZERO GATE VOLTAGE DRAIN CURRENT		_				
$V_{DS} = 0.8 \text{ x Max. rate}$	•	I_{DSS}	-	-	250	μΑ
	$T_J = 125^{\circ}C$					
GATE TO SOURCE LEAKAGE FORWARD	$V_{GS} = 20V$	I_{GSS}	-	-	100	nA
GATE TO SOURCE LEAKAGE REVERSE	$V_{GS} = -20V$				-100	
TURN ON DELAY TIME	$V_{DD} = 50V$,	$t_{d(ON)}$	-	-	35	
RISE TIME	$I_D = 38A$,	t _r			190	nsec
TURN OFF DELAY TIME	$R_G = 2.35\Omega$	t _{d(OFF)}			170	
FALL TIME		t _f			130) / I/
DIODE FORWARD VOLTAGE $T_C = 25$	5°C, I _S = 38A,	V_{SD}	-	-	1.8	Volts
DEVEDOS DECOVEDA TIME	$V_{GS} = 0V$	4			500	
REVERSE RECOVERY TIME	$T_{J} = 25^{\circ}C,$	t _{rr}	-	-	500	
4:/4- < 400	$I_F = 38A$,					nsec
di/ds ≤ 100A/μse		-		2700		
INPUT CAPACITANCE	$V_{GS} = 0 V$	C _{iss}	-	3700	-	
OUTPUT CAPACITANCE	$V_{DS} = 25 \text{ V}$	Coss		1100		pF
REVERSE TRANSFER CAPACITANCE	f = 1.0MHz	C_{rss}		200		



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MECHANICAL DIMENSIONS: in Inches / mm



PINOUT TABLE

DEVICE TYPE	PIN 1	PIN 2	PIN 3
MOSFET, SURFACE MOUNT SHD-5, 5A, 5B PACKAGE	DRAIN	SOURCE	GATE



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